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SEMICONDUCTOR

## 74LVQ14 Low Voltage Hex Inverter with Schmitt Trigger Input

#### **General Description**

The LVQ14 contains six inverter gates each with a Schmitt trigger input. They are capable of transforming slowly changing input signals into sharply defined, jitter-free output signals. In addition, they have a greater noise margin than conventional inverters.

The LVQ14 has hysteresis between the positive-going and negative-going input thresholds (typically 1.0V) which is determined internally by transistor ratios and is essentially insensitive to temperature and supply voltage variations.

#### **Features**

- Ideal for low power/low noise 3.3V applications
- Guaranteed simultaneous switching noise level and dynamic threshold performance

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- Guaranteed pin-to-pin skew AC performance
- **G**uaranteed incident wave switching into 75Ω

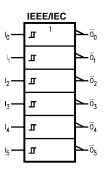
**Connection Diagram** 

#### **Ordering Code:**

Order Number	Package Number	Package Description					
74LVQ14SC	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow					
74LVQ14SJ M14D 14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide							

"X" to the ordering code

#### Logic Symbol



# ō, GND

#### **Pin Descriptions**

Pin Names	Description		
I <sub>n</sub>	Inputs		
Ōn	Outputs		

## **Truth Table**

Input	Output		
I	ō		
L	Н		
Н	L		

H = HIGH Voltage Level L = LOW Voltage Level

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#### Absolute Maximum Ratings(Note 1)

Supply Voltage (V <sub>CC</sub> )	-0.5V to +7.0V
DC Input Diode Current (I <sub>IK</sub> )	
$V_{I} = -0.5V$	–20 mA
$V_{I} = V_{CC} + 0.5V$	+20 mA
DC Input Voltage (VI)	-0.5V to V <sub>CC</sub> + 0.5V
DC Output Diode Current (I <sub>OK</sub> )	
$V_{O} = -0.5V$	–20 mA
$V_O = V_{CC} + 0.5V$	+20 mA
DC Output Voltage (V <sub>O</sub> )	-0.5V to V <sub>CC</sub> + 0.5V
DC Output Source	
or Sink Current (I <sub>O</sub> )	±50 mA
DC V <sub>CC</sub> or Ground Current	
(I <sub>CC</sub> or I <sub>GND</sub> )	±200 mA
Storage Temperature (T <sub>STG</sub> )	-65°C to +150°C
DC Latch-Up Source or	
Sink Current	±100 mA

## Recommended Operating Conditions (Note 2)

Supply Voltage (V <sub>CC</sub> )	
LVQ	2.0V to 3.6V
Input Voltage (V <sub>I</sub> )	0V to V <sub>CC</sub>
Output Voltage (V <sub>O</sub> )	0V to V <sub>CC</sub>
Operating Temperature (T <sub>A</sub> )	$-40^{\circ}C$ to $+85^{\circ}C$
Minimum Input Edge Rate ( $\Delta V/\Delta t$ )	
V <sub>IN</sub> from 0.8V to 2.0V	
V <sub>CC</sub> @ 3.0V	125 mV/ns

Note 1: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

#### **DC Electrical Characteristics**

Symbol	Parameter Minimum High Level	Vcc	$T_A = +25^{\circ}C$		$T_A = -40^{\circ}C$ to $+85^{\circ}C$	Units	Conditions	
		(V)	Typ Guaranteed Limits		uaranteed Limits	Units	Conditions	
V <sub>OH</sub>		3.0	2.99	2.9	2.9	V	I <sub>OUT</sub> = -50 μA	
	Output Voltage	3.0		2.58	2.48	V	$V_{IN} = V_{IL} \text{ or } V_{IH} \text{ (Note 3)}$ $I_{OH} = -12 \text{ mA}$	
V <sub>OL</sub>	Maximum Low Level	3.0	0.002	0.1	0.1	V	I <sub>OUT</sub> = 50 μA	
	Output Voltage	3.0		0.36	0.44	V	$V_{IN} = V_{IL} \text{ or } V_{IH} \text{ (Note 3)}$ $I_{OL} = 12 \text{ mA}$	
I <sub>IN</sub>	Maximum Input Leakage Current	3.6		±0.1	±1.0	μΑ	$V_I = V_{CC}, GND$	
V <sub>t+</sub>	Maximum Positive Threshold	3.0		2.2	2.2	V	T <sub>A</sub> = Worst Case	
V <sub>t-</sub>	Minimum Negative Threshold	3.0		0.5	0.5	V	T <sub>A</sub> = Worst Case	
V <sub>h(max)</sub>	Maximum Hysteresis	3.0		1.2	1.2	V	T <sub>A</sub> = Worst Case	
V <sub>h(min)</sub>	Minimum Hysteresis	3.0		0.3	0.3	V	T <sub>A</sub> = Worst Case	
I <sub>OLD</sub>	Minimum Dynamic	3.6			36	mA	V <sub>OLD</sub> = 0.8V Max (Note 5)	
I <sub>OHD</sub>	Output Current (Note 4)	3.6			-25	mA	V <sub>OHD</sub> = 2.0V Min (Note 5)	
Icc	Maximum Quiescent Supply Current	3.6		2.0	20.0	μΑ	$V_{IN} = V_{CC} \text{ or } GND$	
V <sub>OLP</sub>	Quiet Output Maximum Dynamic V <sub>OL</sub>	3.3	0.9	1.1	· · · · · · · · · · · · · · · · · · ·		(Note 6)(Note 7)	
V <sub>OLV</sub>	Quiet Output Minimum Dynamic V <sub>OL</sub>	3.3	-0.8	-1.1	l v		(Note 6)(Note 7)	
V <sub>IHD</sub>	Maximum High Level Dynamic Input Voltage	3.3	1.9	2.0	V		(Note 6)(Note 8)	
V <sub>ILD</sub>	Maximum Low Level Dynamic Input Voltage	3.3	1.3	2.0		V	(Note 6)(Note 8)	

Note 3: All outputs loaded; thresholds on input associated with output under test.

Note 4: Maximum test duration 2.0 ms, one output loaded at a time.

Note 5: Incident wave switching on transmission lines with impedances as low as 75Ω for commercial temperature range is guaranteed for 74LVQ. Note 6: Worst case package.

Note 7: Max number of outputs defined as (n). Data inputs are driven 0V to 3.3V; one output at GND.

Note 8: Max number of Data Inputs (n) switching. (n - 1) inputs switching 0V to 3.3V. Input-under-test switching: 3.3V to threshold ( $V_{ILD}$ ), 0V to threshold ( $V_{IHD}$ ), f = 1 MHz.

#### **AC Electrical Characteristics**

			T <sub>A</sub> = +25°C C <sub>L</sub> = 50 pF			$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$ $C_L = 50 \text{ pF}$		Units	
Symbol	Parameter	V <sub>CC</sub> (V)							
			Min	Тур	Max	Min	Max		
t <sub>PLH</sub>	Propagation Delay	2.7	1.5	11.4	19.0	1.5	21.0		
		$3.3\pm 0.3$	1.5	9.5	13.5	1.5	15.0	ns	
t <sub>PHL</sub>	Propagation Delay	2.7	1.5	9.0	16.2	1.5	19.0		
		$3.3\pm 0.3$	1.5	7.5	11.5	1.5	13.0	ns	
t <sub>OSHL,</sub>	Output to Output Skew	2.7		1.0	1.5		1.5	1	
tosi H	Data to Output (Note 9)	$3.3\pm0.3$		1.0	1.5		1.5	ns	

Note 9: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t<sub>OSHL</sub>) or LOW-to-HIGH (t<sub>OSLH</sub>). Parameter guaranteed by design.

#### Capacitance

Symbol	Parameter	Тур	Units	Conditions
C <sub>IN</sub>	Input Capacitance	4.5	pF	V <sub>CC</sub> = Open
C <sub>PD</sub> (Note 10)	Power Dissipation Capacitance	20	pF	$V_{CC} = 3.3V$

Note 10: C<sub>PD</sub> is measured at 10 MHz.

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